

Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

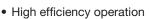
Ultra Low $V_F = 0.42 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V_{RRM}	45 V			
I _{FSM}	100 A			
V _F at I _F = 10 A (T _A = 125 °C)	0.54 V			
T _J max.	150 °C			
Package	TO-220AB			
Diode variations	Common cathode			

FEATURES

- Power pack
- · Trench MOS Schottky technology
- · Low forward voltage drop, low power losses



RoHS

• Solder dip 275 °C max. 10 s, per JESD 22-B106

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VE2045C-E3	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	А	
	per diode		10		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	100	А	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.50	-	V	
	I _F = 10 A			0.60	0.70		
	I _F = 5 A	T _A = 125 °C		0.42	-		
	I _F = 10 A			0.54	0.63		
Reverse current per diode	V _R = 45 V	, T _A = 25 °C	I _R ⁽²⁾	-	500	μΑ	
	V _R = 45 V	T _A = 125 °C		3	15	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VE2045C-E3	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.5	°C/W	
	per device		2.2		
	per device	R ₀ JA (1)(2)	55]	

Notes

⁽²⁾ Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VE2045C-E3/45	1.93	45	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

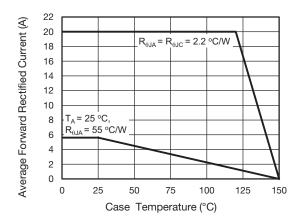


Fig. 1 - Maximum Forward Current Derating Curve

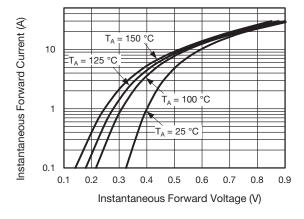


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

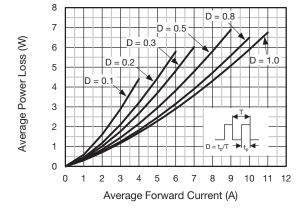


Fig. 2 - Forward Power Loss Characteristics Per Diode

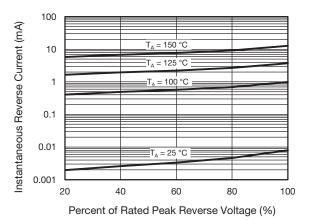
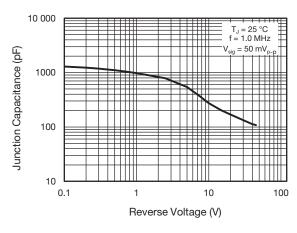


Fig. 4 - Typical Reverse Characteristics Per Diode

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $\Delta P_D/\Delta T_J < 1$ R_{8,JA}



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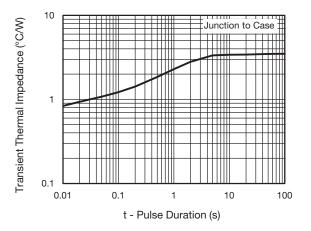
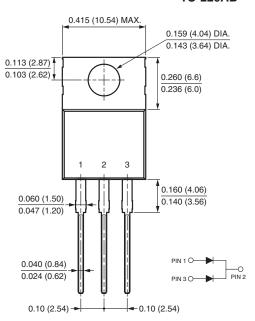
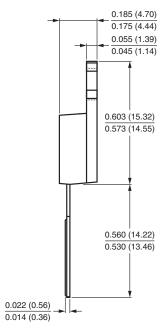


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB







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